

TCVCXO 3V, Ceramic SMD

Technical Data S6800 Series





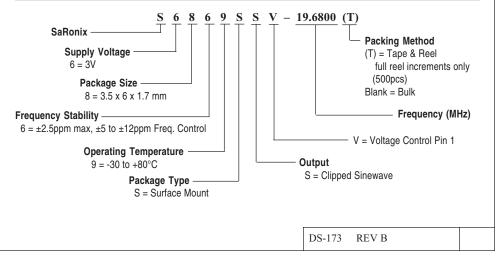
Description

A surface mountable, digitally temperature compensated crystal oscillator for 3Volt operation. The sub-miniature size, extremely low profile and low power consumption of this TCVCXO makes it ideally suited for portable, wireless applications such as cellular telephones and networking. The hermetically sealed ceramic package is fully compatible with standard surface mounting processes.

Applications & Features

- Cellular Telephones (GSM, PDC, TDMA, CDMA)
- GPS
- Mobile and Portable Radio/Telephone
- Communications Transceivers
- 3 Volt operation
- Sub-miniature 3.5 x 6 mm, very low profile 1.7mm max height package
- Hermetically sealed, compatible with standard board washing techniques
- Available on tape & reel; 16mm tape, 500pcs per reel

Frequencies:	12.80, 13.00, 14.40, 16.384, 16.80, 19.20, 19.44, 19.68, 19.8 MHz
Frequency Stability:	vs. temperature: ± 2.5 ppm max vs. supply voltage: ± 0.3 ppm max vs. aging: ± 1 ppm max per year, ± 3.5 ppm / 5yrs, ± 6 ppm / 10yrs (@ 40°C Average Ambient Operating Temperature) vs. load: ± 0.3 ppm max, CL: ($[10k\Omega // 10 pF] \pm 10\%$)
Temperature Range:	
Operating:	-30 to +80°C
Supply Voltage:	3V ±10%
Supply Current:	1.5mA max (12.8 to 13 MHz), 2.0mA max(14.4 to 19.8 MHz)
Output: Clipped Sinewave Level: Load:	0.9V peak-to-peak min 10KΩ // 10pF
Frequency Control Range:	± 5 to ± 12 ppm, 0.5 to 2.5V
Control Voltage:	1.5V ±1.0V
Phase Noise:	-40 dBc/Hz @ 1Hz -90 dBc/Hz @ 10Hz -112 dBc/Hz @ 100Hz -130 dBc/Hz @ 1kHz -145 dBc/Hz @ 10kHz -148 dBc/Hz @ 100kHz
Mechanical:	
Shock: Solderability: Vibration: Solvent Resistance: Resistance to Soldering Heat:	MIL-STD-883, Method 2002, Condition B MIL-STD-883, Method 2003 MIL-STD-883, Method 2007, Condition A MIL-STD-202, Method 215 MIL-STD-202, Method 210, Condition I
Environmental:	
Gross Leak Test: Fine Leak Test: Thermal Shock:	MIL-STD-883, Method 1014, Condition C MIL-STD-883, Method 1014, Condition A2 MIL-STD-883, Method 1011, Condition A MIL-STD-202, Method 103, Condition C





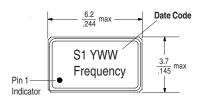
TCVCXO

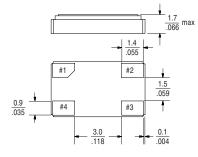
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Package Details

1 = ±2.5ppm, ±5 to 12ppm FC, -30 to +80°C Y = year: 1 = 2001, 2 = 2002, 3 = 2003 etc. WW = week





Pad Configurations

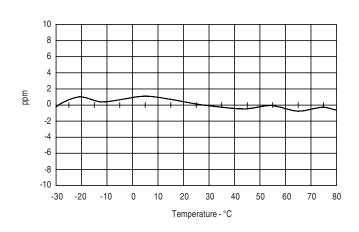
Pad 1 = Control Voltage

Pad 2 = GND

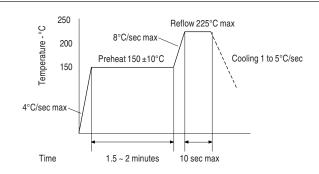
Pad 3 = Output

Pad 4 = V_{DD}

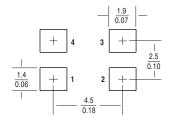
Typical Frequency vs. Temperature Characteristics



Solder Reflow Guide

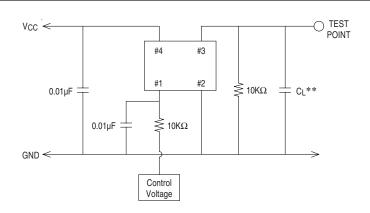


Recommended Land Pattern



Scale: None (Dimensions in $\frac{mm}{inches}$

Test Circuit



** $C_L = 10pF$ (Including probe and jig capacitance)

All specifications are subject to change without notice.

DS-173 REV B